TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74ACT273P,TC74ACT273F,TC74ACT273FW

#### Octal D-Type Flip Flop with Clear

The TC74ACT273 is an advanced high speed CMOS OCTAL D-TYPE FLIP FLOP fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the  $\overline{\text{CLR}}$  input is held "L", the Q outputs are at a low logic level independent of the other inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **Features**

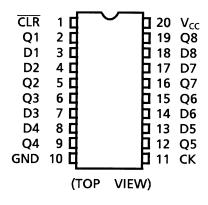
- High speed:  $f_{max} = 170 \text{ MHz}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation: I<sub>CC</sub> = 8 μA (max) at Ta = 25°C
- Compatible with TTL outputs:  $V_{IL} = 0.8 \text{ V (max)}$

 $V_{IH} = 2.0 \text{ V (min)}$ 

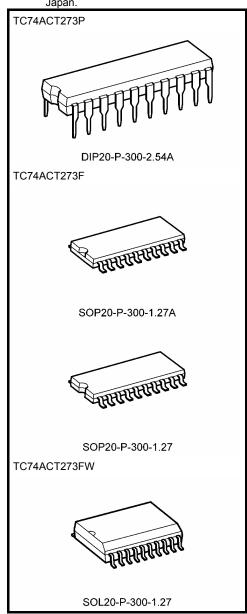
• Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24$  mA (min) Capability of driving 50  $\Omega$  transmission lines.

- Balanced propagation delays: t<sub>pLH</sub> ≃ t<sub>pHL</sub>
- Pin and function compatible with 74F273

#### **Pin Assignment**



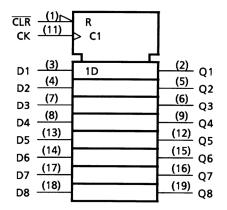
Note: xxxFW (JEDEC SOP) is not available in Japan.



Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.) SOP20-P-300-1.27 : 0.22 g (typ.) SOL20-P-300-1.27 : 0.46 g (typ.)

# **IEC Logic Symbol**

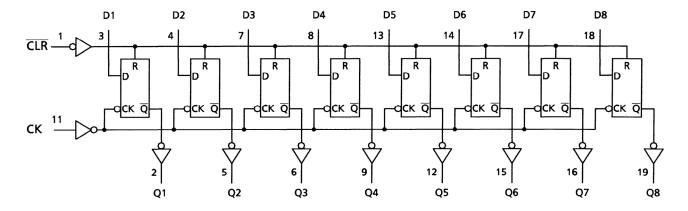


### **Truth Table**

	Inputs		Output	Function		
CLR	D CK		Q	i unction		
L	Х	Х	L	Clear		
Н	L		L	_		
Н	Н		Н	_		
Н	Х		Qn	No Change		

X: Don't care

### **System Diagram**





### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	−0.5 to V <sub>CC</sub> + 0.5	٧
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	–65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

### **Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5 to 5.5	٧
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		- Unit	
Onaraciensilos Symbo					V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
High-level input voltage	V <sub>IH</sub>		_			2.0	_	_	2.0	_	V
Low-level input voltage	V <sub>IL</sub>	_			4.5 to 5.5	_	_	0.8	_	0.8	V
	Voн	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -50 \mu A$		4.5	4.4	4.5	_	4.4	_	
High-level output voltage			$I_{OH} = -24 \text{ mA}$		4.5	3.94	_	_	3.80	_	٧
			$I_{OH} = -75 \text{ mA}$	(Note)	5.5	_	_	_	3.85	_	
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA		4.5	_	0.0	0.1	_	0.1	
Low-level output voltage			I <sub>OL</sub> = 24 mA		4.5	_	_	0.36	_	0.44	V
			$I_{OL} = 75 \text{ mA}$	(Note)	5.5	_	_	_	_	1.65	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μА	
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_C$	<sub>C</sub> or GND		5.5	_	_	8.0	_	80.0	μА
	IC	Per input: V <sub>IN</sub> = 3.4 V		<i></i>			4.05		4.5	mA	
		Other inp	out: V <sub>CC</sub> or GND		5.5		_	1.35		1.5	IIIA

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

### Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = Ta = -40 t 25°C 85°C			
			V <sub>CC</sub> (V)	Limit	Limit		
Minimum pulse width	t <sub>W (L)</sub>		5.0 ± 0.5	5.0	5.0	ns	
(CK)	t <sub>W (H)</sub>	_	5.0 ± 0.5	5.0	0.0	113	
Minimum pulse width	to a s		5.0 ± 0.5	5.0	5.0	ns	
(CLR)	t <sub>W (L)</sub>	_	5.0 ± 0.5	5.0	5.0	115	
Minimum set-up time	ts	_	$5.0 \pm 0.5$	3.5	3.5	ns	
Minimum hold time	t <sub>h</sub>	_	$5.0 \pm 0.5$	1.5	1.5	ns	
Minimum removal time ( $\overline{\text{CLR}}$ )	t <sub>rem</sub>	_	5.0 ± 0.5	3.0	3.0	ns	



### AC Characteristics (CL = 50 pF, RL = 500 $\Omega$ , input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	01
Propagation delay time (CK-Q)	t <sub>pLH</sub>	_	5.0 ± 0.5	_	6.6	10.5	1.0	12.0	ns
Propagation delay time ( CLR -Q)	t <sub>pHL</sub>	_	5.0 ± 0.5	_	7.4	10.8	1.0	12.3	ns
Maximum clock frequency	f <sub>max</sub>	_	5.0 ± 0.5	80	150	_	80		MHz
Input capacitance	C <sub>IN</sub>	_		_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub> (Note)	_		_	34	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$  (per F/F)

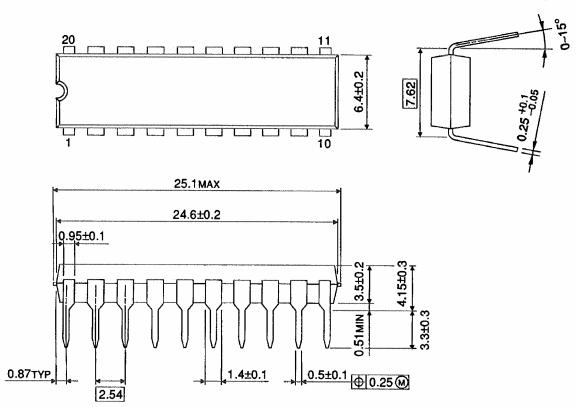
And the total  $C_{\mbox{\scriptsize PD}}$  when n pcs. of Flip Flop operate can be gained by the following equation.

$$C_{PD}$$
 (total) = 23 + 11·n

# **Package Dimensions**

DIP20-P-300-2.54A Unit : mm

★ %

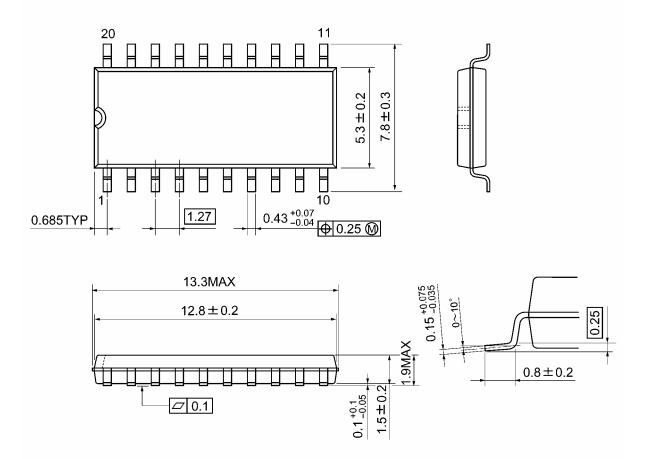


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Weight: 1.30 g (typ.)

# **Package Dimensions**

SOP20-P-300-1.27A Unit: mm



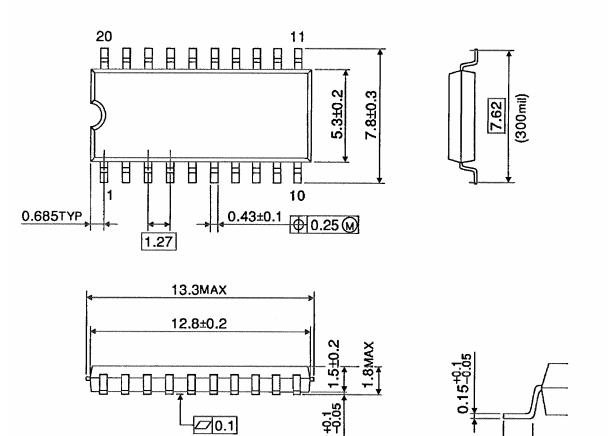
Weight: 0.22 g (typ.)

0.8±0.2

# **TOSHIBA**

# **Package Dimensions**

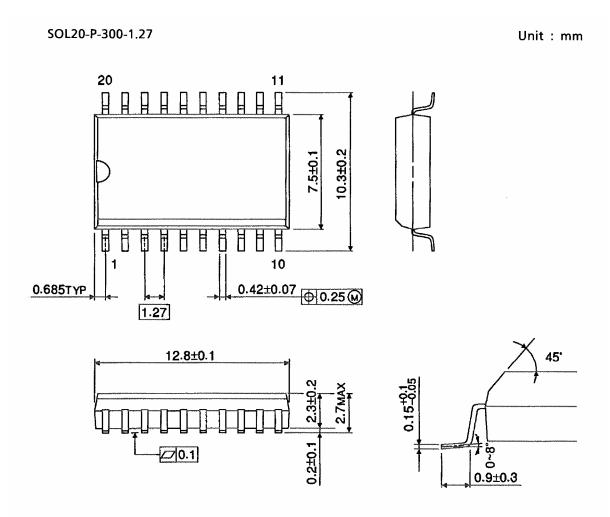
SOP20-P-300-1.27 Unit: mm



8

Weight: 0.22 g (typ.)

# **Package Dimensions (Note)**



Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Note: Lead (Pb)-Free Packages

DIP20-P-300-2.54A SOP20-P-300-1.27A

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